

KSP12

Darlington Transistor

Collector-Emitter Voltage: V_{CES}=20V
Collector Power Dissipation: P_C (max)=625mW



1. Emitter 2. Base 3. Collector

NPN Epitaxial Silicon Darlington Transistor

Absolute Maximum Ratings Ta=25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|------------------|-----------------------------|-----------|-------|
| V _{CES} | Collector-Emitter Voltage | 20 | V |
| V _{EBO} | Emitter-Base Voltage | 10 | V |
| P _C | Collector Power Dissipation | 625 | mW |
| T _J | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | -55 ~ 150 | °C |

Electrical Characteristics T_a=25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|-----------------------|--------------------------------------|--|------|------|------|-------|
| BV _{CES} | Collector-Emitter Breakdown Voltage | I _C =100μA, I _B =0 | 20 | | | V |
| I _{CBO} | Collector Cut-off Current | V_{CB} =15V, I_{E} =0 | | | 100 | nA |
| I _{CES} | Collector Cut-off Current | V_{CE} =15V, I_{B} =0 | | | 100 | nA |
| I _{EBO} | Emitter Cut-off Current | V _{EC} =10V, I _C =0 | | | 100 | nA |
| h _{FE} | DC Current Gain | V _{CE} =5V, I _C =10mA | 20K | | | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C =10mA, I _B =0.01mA | | | 1 | V |
| V _{BE} (on) | Base-Emitter On Voltage | V _{CE} =5V, I _C =10mA | | | 1.4 | V |

 $I_{\rm C} = 1000 \; I_{\rm B}$

Typical Characteristics

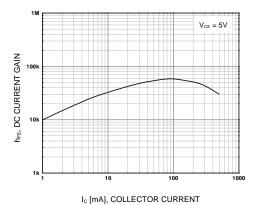


Figure 1. DC current Gain

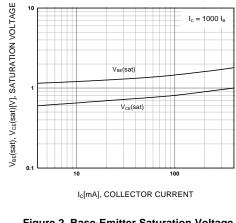


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

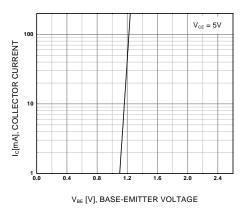


Figure 3. Base-Emitter On Voltage

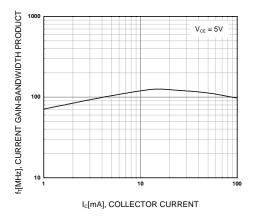
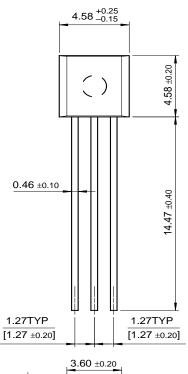


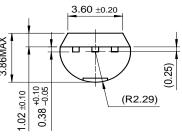
Figure 4. Current Gain Bandwidth Product

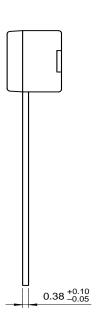
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Package Dimensions

TO-92







Dimensions in Millimeters

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| CROSSVOLT™ | FRFET™ | MicroPak™ | QFET™ | SuperSOT™-8 |
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|--------------------------|---------------------------|---|
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